



VOLTAGE REFERENCE ARRAY

Features

- Epitaxial Planar Die Construction
- Ideally Suited for Automated Assembly Processes
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

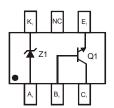
Mechanical Data

- Case: SOT26 (SC74R)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Matte Tin Finish Annealed over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
 Ordering Information: See Page 4
 Weight: 0.008 grams (Approximate)

SOT26 (SC74R)



Top View



Device Schematic

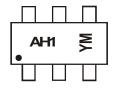
Ordering Information (Note 4)

Part Number	Case	Packaging
DVRN6056-7-F	SOT26 (SC74R)	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3).compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



AH1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

Year	2003	2004	2005		2012	2013	2014	2015	2016	2017	2018	2019	2020
Code	Р	R	S		Z	Α	В	С	D	Е	F	G	Н
Month	Jan	Feb	Mar	Apr	Ma	y Jı	un	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	(6	7	8	9	0	N	D



Maximum Ratings, NPN Transistor Element (Q1) (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current - Continuous (Note 5)	Ic	600	mA

Maximum Ratings, Zener Element (Z1) (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Forward Voltage	@ I _F = 10mA	V _F	0.9	V

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_{D}	300	mW
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	417	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Note: 5. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.

Electrical Characteristics, NPN Transistor Element (Q1) (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 6)							
Collector-Base Breakdown Voltage	V _{(BR)CBO}	60	_	V	$I_C = 100\mu A, I_E = 0$		
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	40	_	V	$I_C = 1.0 \text{mA}, I_B = 0$		
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	6		V	$I_E = 100 \mu A, I_C = 0$		
Collector Cutoff Current	I _{CEX}		100	nA	$V_{CE} = 35V$, $V_{EB(OFF)} = 0.4V$		
Base Cutoff Current	I_{BL}	_	100	nA	$V_{CE} = 35V, V_{EB(OFF)} = 0.4V$		
ON CHARACTERISTICS (Note 6)							
		20	_		$I_C = 100 \mu A, V_{CE} = 1.0 V$		
		40	_		$I_C = 1.0 \text{mA}, V_{CE} = 1.0 \text{V}$		
DC Current Gain	h _{FE}	80	_	_	$I_C = 10 \text{mA}, V_{CE} = 1.0 \text{V}$		
		100	300		$I_C = 150 \text{mA}, V_{CE} = 1.0 \text{V}$		
		40			$I_C = 500 \text{mA}, V_{CE} = 2.0 \text{V}$		
Collector-Emitter Saturation Voltage	V		0.40	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$		
Collector-Efficiel Saturation voltage	V _{CE(SAT)}		0.75	٧	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$		
Base-Emitter Saturation Voltage	\/	0.75	0.95	V	$I_C = 150 \text{mA}, I_B = 15 \text{mA}$		
Dase-Enniter Saturation voltage	V _{BE(SAT)}	_	1.2	V	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$		

Electrical Characteristics, Zener Element (Z1) (@T_A = +25°C, unless otherwise specified.)

Zener Voltage Range (Note 6)			Maxir	num Zener Impedance	Maximum Reverse Leakage Current (Note 6)		
	Vz @ Izt		I _{ZT}	Z _{ZT} @ I _{ZT}	$Z_{ZK} @ I_{ZK} = 0.5mA$	I _R	@ V _R
Nom (V)	Min (V)	Max (V)	mA	Ω		μA	٧
5.6	5.49	5.73	5	60	200	1.0	2.5

Note: 6. Short duration pulse test used to minimize self-heating effect.



NPN Transistor (Q1)

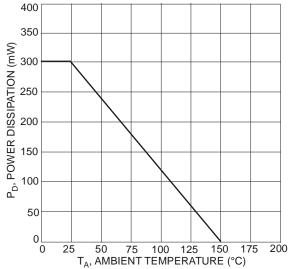


Fig. 1 Power Dissipation vs. Ambient Temperature (Total Device)

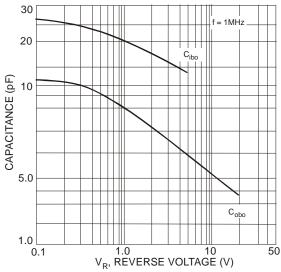


Fig. 3 Typical Capacitance Characteristics

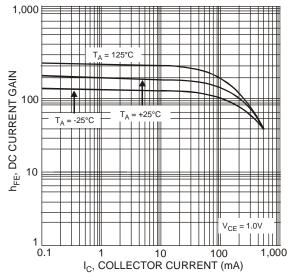


Fig. 2 Typical DC Current Gain vs. Collector Current

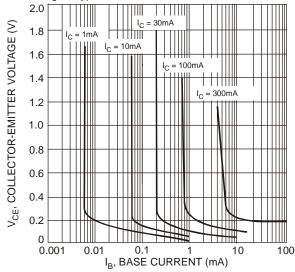


Fig. 4 Typical Collector Saturation Region



NPN Transistor (Q1) (Continued)

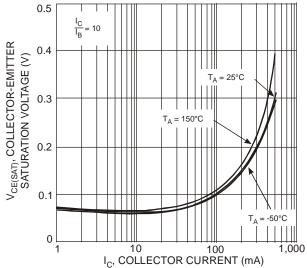


Fig. 5 Typical Collector-Emitter Saturation Voltage vs. Collector Current

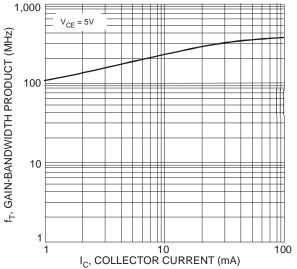


Fig. 7 Typical Gain-Bandwidth Product vs. Collector Current

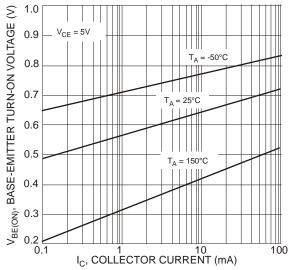
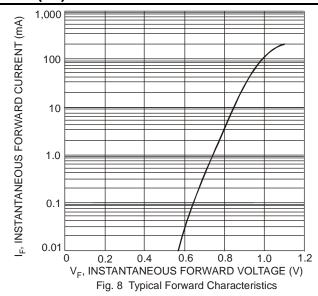


Fig. 6 Typical Base-Emitter Turn-On Voltage vs. Collector Current



Zener (Z1)

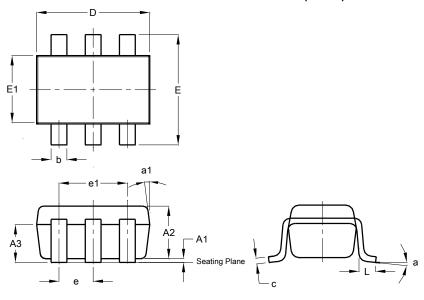




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26 (SC74R)

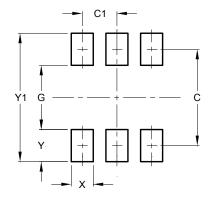


;	SOT26 (SC74R)							
Dim	Min	Max	Тур					
A1	0.013	0.10	0.05					
A2	1.00	1.30	1.10					
А3	0.70	0.80	0.75					
b	0.35	0.50	0.38					
С	0.10	0.20	0.15					
D	2.90	3.10	3.00					
е	-	-	0.95					
e1	-	-	1.90					
Е	2.70	3.00	2.80					
E1	1.50	1.70	1.60					
L	0.35	0.55	0.40					
а	-	-	8°					
a1	-	-	7°					
All Dimensions in mm								

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26 (SC74R)



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Y	0.80
V1	3.20



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